

Pin Descriptions

LMV331	LMV331				
Pin Name	Pin #	Function			
IN+	1	Non-Inverting Input			
V _{EE}	2	Chip Supply Voltage(Negative)/GND			
IN-	3	Inverting Input			
OUT	4	Output			
V _{cc}	5	Chip Supply Voltage(Positive)			
LMV393					
10UT	1	Channel 1 Output			
1IN-	2	Channel 1 Inverting Input			
1IN+	3	Channel 1 Non-inverting Input			
V _{EE}	4	Chip Supply Voltage(Negative)/GND			
2IN+	5	Channel 2 Non-inverting Input			
2IN-	6	Channel 2 Inverting Input			
2OUT	7	Channel 2 Output			
V _{CC}	8	Chip Supply Voltage(Positive)			

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description		Rating	Unit
ESD HBM	Human Body Model ESD Protection		6.0	KV
ESD MM	Machine Model ESD Protection		200	V
V _{ID}	Differential Input Voltage		±Supply Voltage	V
V _{CC} -V _{EE}	Supply Voltage		5.5	V
		SOT353 (Note 5)	371	
0	θ _{JA} Thermal Resistance Junction-to- Ambient	SOT25 (Note 5)	204	°C/W
ÐJA		SO-8 (Note 5)	120	
		MSOP-8 (Note 5)	180	
T _{ST}	Storage Temperature		-65 to +150	°C
TJ	Maximum Junction Temperature		+150	°C

 Stresses greater than the 'Absolute Maximum Ratings' specified above, may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be effected by exposure to absolute maximum rating conditions for extended periods of time.
All numbers are typical, and apply for packages soldered directly onto a PC board in still air. Notes:

Recommended Operating Conditions (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
V _{CC} -V _{EE}	Supply Voltage	2.7 to 5.5	V
T _A	Operating Ambient Temperature Range	-40 to +125	°C





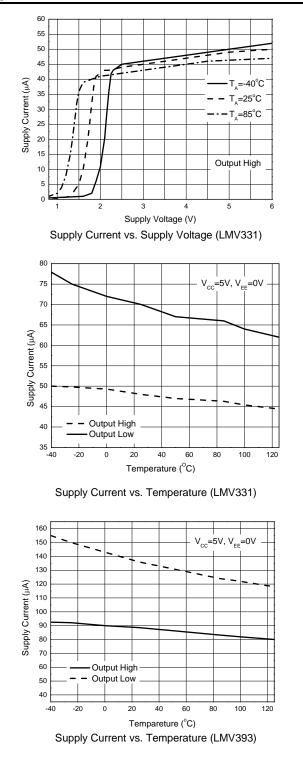
Electrical Characteristics (Notes 6 & 7) (@T_A = +25°C, V_{EE} = 0V, V_{CM} = 0V and R_L = 5.1KΩ, unless otherwise specified.)

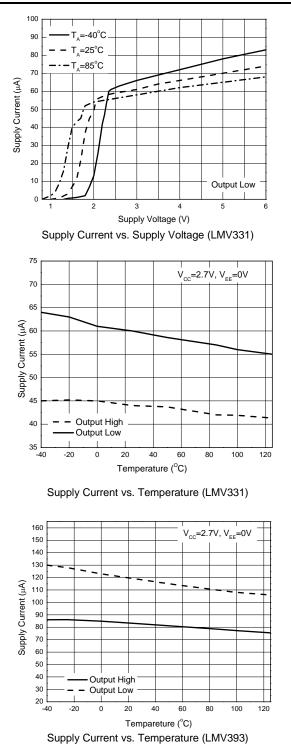
Symbol	Parameter		Test Conditions	Min	Тур	Max	Unit	
7V DC Electr	rical Characteristic	s					•	
Vos	Input Offset Voltage		-	-	1.7	7	mV	
TCV _{OS}	Input Offset Volta	-	T _A = full range	-	5	-	µV/°C	
I _B Input Bias Current			-	-	10	250		
		t	T _A = full range	-	_	400	nA	
			-	-	5	50		
los	Input Offset Curre	ent	T _A = full range	-	-	150	nA	
V _{CM}	Common-Mode Ir	nput Voltage Range	-	-0.1	-	+2.0	V	
VSAT	Saturation Voltag		I _{SINK} ≤ 1mA	-	120	-	mV	
IO	Output Sink Curre		V ₀ ≤ 1.5V	5	23	-	mA	
10			v0=1.5v	-	0.003	_	ША	
IOL	Output Leakage (Current	T _A = full range	_	0.003	1	μA	
		LMV331		-	40	100	μA	
Is	Supply Current	LMV393	-	-			μA	
13	Supply Sunon	(Both Comparators)	-	-	70	150	uA	
7V AC Electr	rical Characteristic							
			Input overdrive= 10mV	-	1,000	-	ns	
t PHL	Propagation dela	y high to low	Input overdrive= 100mV	-	350	-	ns	
	D (* 11		Input overdrive= 10mV	-	500	-	ns	
t _{PLH} Propagation delay low to high		Input overdrive= 100mV	-	400	-	ns		
/ DC Electric	al Characteristics							
N/			-	-	1.7	7	mV	
V _{OS}	Input Offset Volta	ge	T _A = full range	-	-	9		
TCV _{OS}	Input Offset Voltage Average Drift		T _A = full range	-	5	-	μV/°C	
			-	-	25	250		
IB	Input Bias Currer	it	$T_A = full range$	-	-	400	nA	
			-	-	2	50	nA	
los	Input Offset Curre	ent	$T_A = full range$	-	-	150		
V _{CM}	Common-Mode I	nput Voltage Range	-	-0.1	-	4.2	V	
Av		erential Voltage Gain	-	20	50	-	V/mV	
7.0	24.90 0.9.14.2	oronnar ronago oann	I _{SINK} ≤ 4mA	-	200	400	mV	
V_{SAT}	Saturation Voltag	e	$I_{SINK} \le 4$ mA, $T_A = full$ range	-	-	700		
lo	Output Sink Curre	ent	V ₀ ≤ 1.5V	10	84	-	mA	
			-	-	0.003	-		
IOL	Output Leakage	Current	T _A = full range	-	-	1	μA	
			-	-	60	120		
		LMV331	T _A = full range	-	-	150	μA	
Is	Supply Current	t LMV393		-	100	200		
		(Both Comparators)	T _A =full range	-	-	250	uA	
AC Electric:	al Characteristics	p. p	- A		1		1	
			Input overdrive = 10mV	-	600	-	ns	
t _{PHL}	Propagation dela	y high to low	Input overdrive = 100mV	-	200	-	ns	
	_		Input overdrive = 10mV	-	450	-	ns	
t _{PLH} Propagation delay low to high		Input overdrive = 100mV	_	300	_	ns		

Notes: 6. Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material. 7. All limits are guaranteed by testing or statistical analysis.



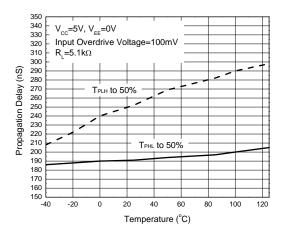
Typical Performance Characteristics (@T_A = +25°C, unless otherwise specified.)



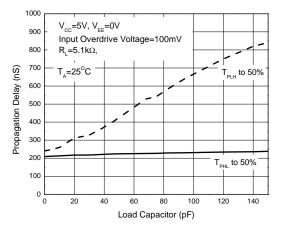




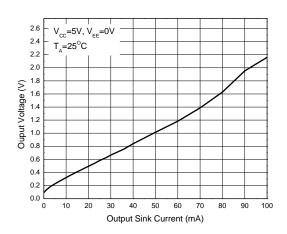
Typical Performance Characteristics (continued) (@ T_A = +25°C, unless otherwise specified.)



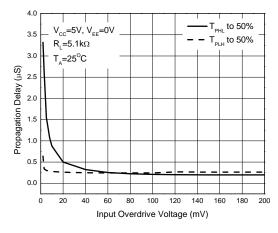
Propagation Delay vs. Temperature



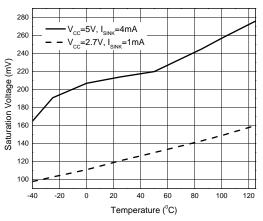
Propagation Delay vs. Load Capacitors



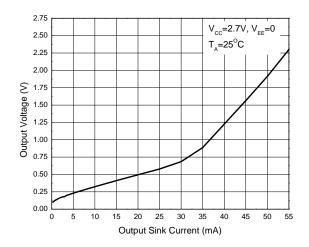
Output Voltage vs. Output Sink Current



Propagation Delay vs. Input Overdrive Voltage



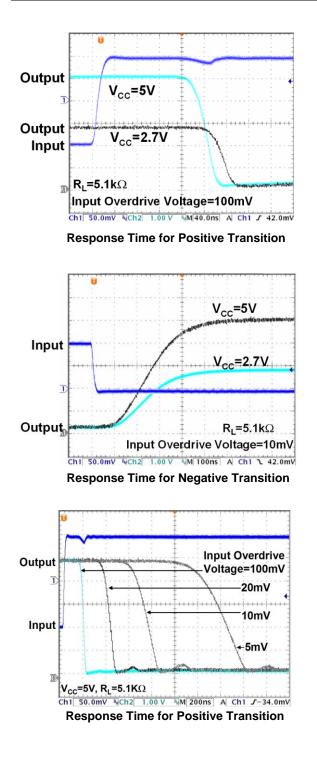
Saturation Voltage vs. Temperature

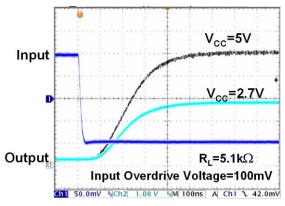


Output Voltage vs. Output Sink Current

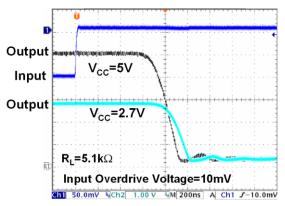


Typical Performance Characteristics (cont.) (@ T_A = +25°C, unless otherwise specified.)

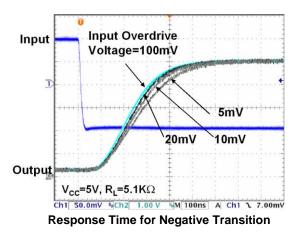




Response Time for Negative Transition



Response Time for Positive Transition





V_{cc}=5V,^UR_L=5.1KΩ

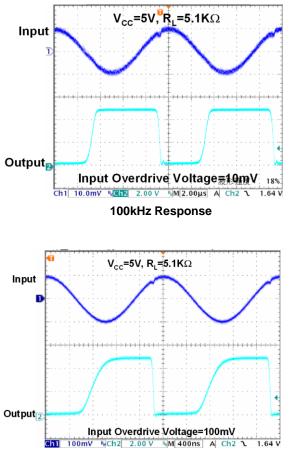
Input Overdrive Voltage=100mV

100kHz Response

Input

Output₂

Typical Performance Characteristics (cont.) (@ T_A = +25°C, unless otherwise specified.)



500kHz Response





Application Information

Detailed Description

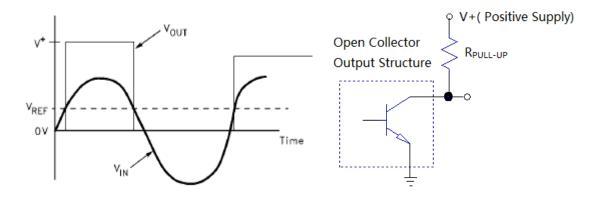
LMV331/LMV393 are low-voltage single/dual general- purpose comparators. They have a single supply operating voltage range from 2.7V to 5.5V; the common mode input voltage range extends from -0.1V below the negative supply to within 0.8V of the positive supply.

The LMV331/393 series is built using the BiCMOS process with bipolar input and output stages for improved noise performance. It is a costeffective solution for portable consumer products where space, low voltage, low power and price are the primary specification in circuit design.

Basic Comparator

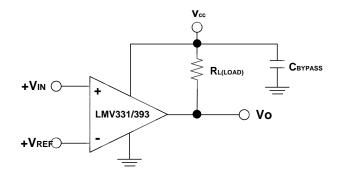
A basic comparator circuit is used for converting analog signal to digital output. The LMV331/393 has open-collector output structure, which required a pull-high resistor to positive supply voltage for the output to switch properly. When the internal output transistor is off, the output voltage will be pulled up to the external positive voltage.

The output pull- up resistor should be chosen high enough so as to avoid excessive power dissipation, yet low enough to supply enough drive to switch whatever load circuitry is used on the comparator output. On the LMV331/393 the pull-up resistor should range between $1K\Omega$ to $10K\Omega$.



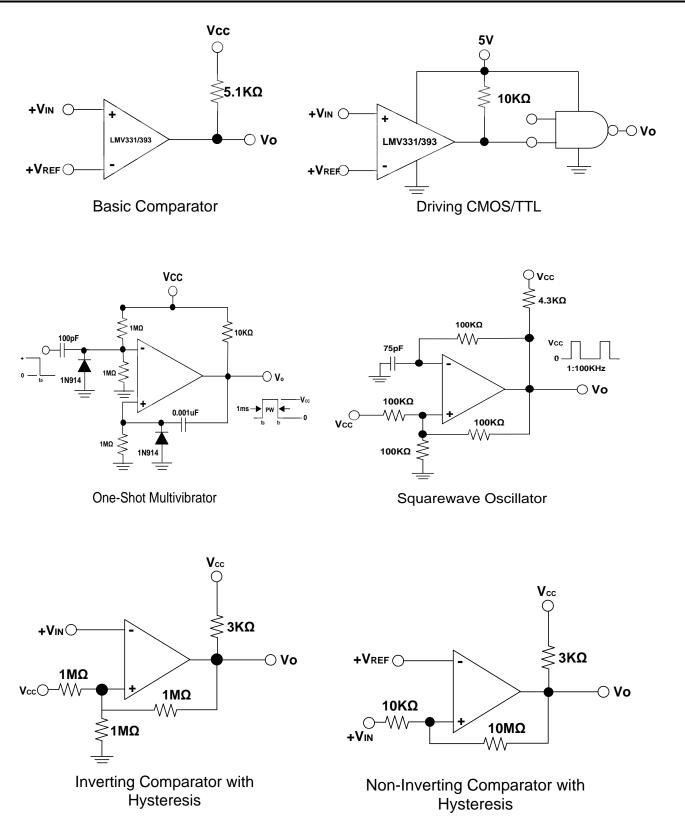
Power Supply Bypassing

For better performance, power supply bypass capacitor is necessary. For a single-supply operation system, a minimum of 0.1µF bypass capacitor should be recommended to place as close as possible between V_{cc} pin and GND.



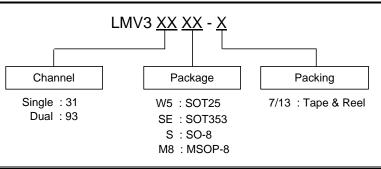


Typical Application Circuit





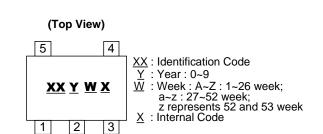
Ordering Information



Part Number Package C	Package Code	de Packaging -	7"/13" Tape and Reel	
	Fackage Code		Quantity	Part Number Suffix
LMV331W5-7	W5	SOT25	3,000/Tape & Reel	-7
LMV331SE-7	SE	SOT353	3,000/Tape & Reel	-7
LMV393S-13	S	SO-8	2,500/Tape & Reel	-13
LMV393M8-13	M8	MSOP-8	2,500/Tape & Reel	-13

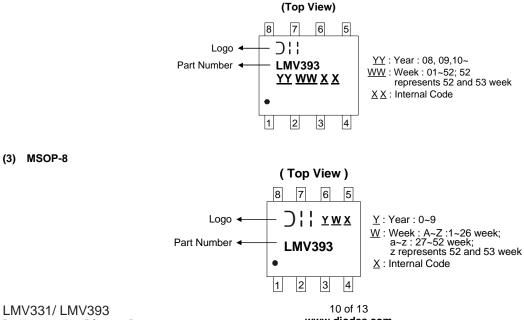
Marking Information

(1) SOT25 and SOT353



Device	Package type	Identification Code
LMV331W5	SOT25	CX
LMV331SE	SOT353	CY

(2) SO-8



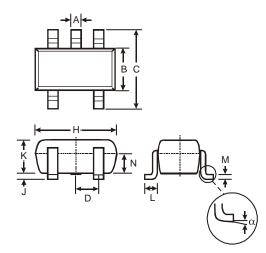
www.diodes.com



Package Outline Dimensions (All dimensions in mm.)

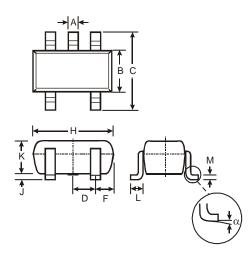
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

(1) Package Type: SOT25



	SOT25			
Dim	Min	Max	Тур	
Α	0.35	0.50	0.38	
в	1.50	1.70	1.60	
с	2.70	3.00	2.80	
D			0.95	
н	2.90	3.10	3.00	
J	0.013	0.10	0.05	
κ	1.00	1.30	1.10	
1	0.35	0.55	0.40	
Σ	0.10	0.20	0.15	
Ν	0.70	0.80	0.75	
α	0°	8°		
All D	All Dimensions in mm			

(2) Package Type: SOT353



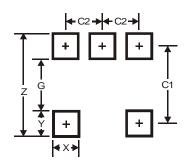
	SOT353				
Dim	Min	Max	Тур		
Α	0.10	0.30	0.25		
В	1.15	1.35	1.30		
С	2.00	2.20	2.10		
D	0	.65 Ty	С		
F	0.40	0.45	0.425		
Н	1.80	2.20	2.15		
J	0	0.10	0.05		
κ	0.90	1.00	1.00		
L	0.25	0.40	0.30		
Μ	0.10	0.22	0.11		
α	0°	8°	-		
All	All Dimensions in mm				



Suggested Pad Layout

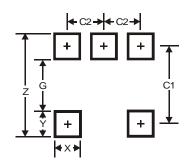
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

(1) Package Type: SOT25



Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Y	0.80
C1	2.40
C2	0.95

(2) Package Type: SOT353



Dimensions	Value (in mm)
Z	2.5
G	1.3
Х	0.42
Y	0.6
C1	1.9
C2	0.65



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